

GE MDS GPA-1

RF Amplifier



CONFIG: GPA-1



SN#1234567

JOB:123456

PRIMARY POWER; 13.8VDC, 8A MAX
OPERATING TEMP; -30 TO +60C

FCC ID: E5MDS-GPA-1

IC: 101D-GPA-1

Model: GPA-1

MADE IN THE U.S.A. BY GE MDS LLC, ROCHESTER, N.Y.